



DirectPath™, Pop-Free 3Vrms Line Driver with Adjustable Gain

Check for Samples: [DRV602](#)

FEATURES

- **DirectPath™**
 - Eliminates Pop/Clicks
 - Eliminates Output DC-Blocking Capacitors
 - Provides Flat Frequency Response 20Hz–20kHz
- **Low Noise and THD**
 - SNR > 102 dB
 - Typical $V_N < 15 \mu\text{Vms}$
 - THD+N < 0.05% 20 Hz–20 kHz
- **Output Voltage into 2.5-k Ω Load**
 - 2 Vrms with 3.3-V Supply Voltage
 - 3 Vrms with 5-V Supply Voltage
- **3Vrms Output Voltage into 2.5 k Ω Load With 5V Supply Voltage**
- **Differential Input**

APPLICATIONS

- Set-Top Boxes
- PDP / LCD TV
- Blu-ray Disc™, DVD-Players
- Home Theater in a Box

DESCRIPTION

The DRV602PW is a 3Vrms pop-free stereo line driver designed to allow the removal of the output dc-blocking capacitors for reduced component count and cost. The device is ideal for single supply electronics where size and cost are critical design parameters.

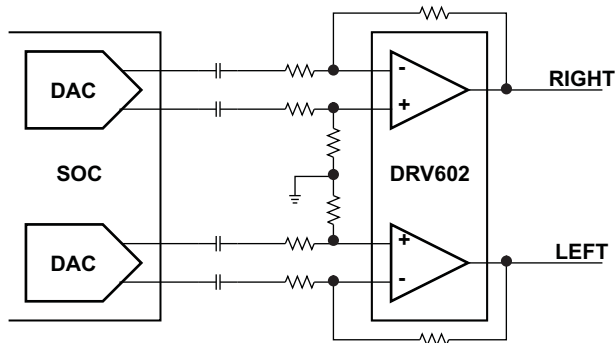
Designed using TI's patented DirectPath™ technology, the DRV602 is capable of driving 3Vrms into a 2.5k Ω load with 5V supply voltage. The device has differential inputs and uses external gain setting resistors, that supports a gain range of $\pm 1\text{V/V}$ to $\pm 10\text{V/V}$. The use of external gain resistors also allows the implementation of a 2nd order low pass filter to compliment DAC's and SOC converters. The line output of the DRV602 has $\pm 8\text{kV}$ IEC ESD protection. The DRV602 (referred to as the '602) has built-in shutdown control for pop-free on/off control.

Using the DRV602 in audio products can reduce component count compared to traditional methods of generating a 3Vrms output. The DRV602 doesn't require a power supply greater than 5V to generate its 8.5V_{pp} output, nor does it require a split rail power supply. The DRV602 integrates its own charge pump to generate a negative supply rail that provides a clean, pop-free ground biased 3Vrms output.

The DRV602 is available in a 14 pin TSSOP package.

If higher SNR, trimmed DC-offset and external undervoltage-mute functions are beneficial in the application, TI recommends the footprint compatible DRV603 ([SLOS617](#)).

For a stereo line and stereo HP driver see DRV604 ([SLOS659](#)).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

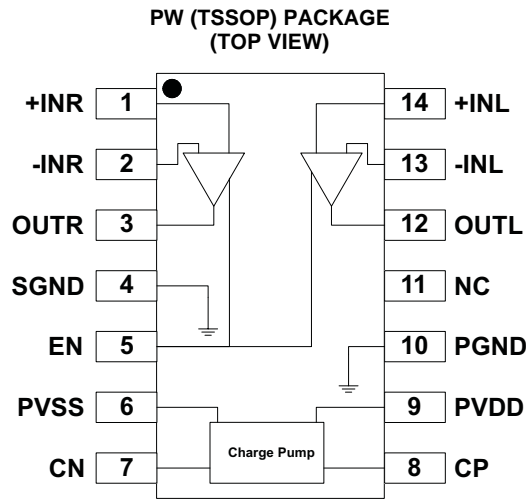
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Blu-ray Disc is a trademark of Blu-ray Disc Association.

All other trademarks are the property of their respective owners.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



PIN FUNCTIONS

| PIN | | I/O ⁽¹⁾ | DESCRIPTION |
|------|------------|--------------------|--|
| NAME | TSSOP (PW) | | |
| +INR | 1 | I | Right channel OPAMP positive input |
| -INR | 2 | I | Right channel OPAMP negative input |
| OTR | 3 | O | Right channel OPAMP output |
| SGND | 4 | I | Signal ground |
| EN | 5 | I | Enable input, active high |
| PVSS | 6 | O | Supply voltage |
| CN | 7 | I/O | Charge pump flying capacitor negative terminal |
| CP | 8 | I/O | Charge pump flying capacitor positive terminal |
| PVDD | 9 | I | Positive supply |
| PGND | 10 | I | Power ground |
| NC | 11 | | No internal connection |
| OUTL | 12 | O | Left channel OPAMP output |
| -INL | 13 | I | Left channel OPAMP negative input |
| +INL | 14 | I | Left channel OPAMP positive input |

(1) I = input, O = output, P = power

ABSOLUTE MAXIMUM RATINGS^{(1) (2)}

over operating free-air temperature range

| | VALUE | UNIT |
|--|--|------|
| Supply voltage, VDD to GND | –0.3 V to 5.5 | V |
| V _I Input voltage | V _{SS} – 0.3 to V _{DD} + 0.3 | V |
| R _L Minimum load impedance | > 600 | Ω |
| EN to GND | –0.3 to V _{DD} +0.3 | V |
| T _J Maximum operating junction temperature range, | –40 to 150 | °C |
| T _{stg} Storage temperature range | –40 to 150 | °C |
| ESD IEC Contact ESD Protection per IEC6100-4-2, on output pins measured on DRV602EVM | ±8 | kV |

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) These voltages represents the DC voltage + peak AC waveform measured at the terminal of the device in all conditions.

DISSIPATION RATINGS

| PACKAGE | θ _{JC} (°/W) | θ _{JA} (°/W) | POWER RATING ⁽¹⁾ AT T _A ≤ 25°C | POWER RATING ⁽¹⁾ AT T _A ≤ 70°C |
|---------------|-----------------------|-----------------------|---|---|
| TSSOP-14 (PW) | 35 | 115 ⁽²⁾ | 870mW | 348mW |

- (1) Power rating is determined with a junction temperature of 125°C. This is the point where performance starts to degrade and long-term reliability starts to be reduced. Thermal management of the final PCB should strive to keep the junction temperature at or below 125°C for best performance and reliability.
- (2) These data were taken with the JEDEC High-K test printed circuit board (PCB). For the JEDEC low-K test PCB, the θ_{JA} is 185°C.

ORDERING INFORMATION

| T _A | PACKAGE ⁽¹⁾ | DESCRIPTION |
|----------------|------------------------|--------------|
| –40°C to 85°C | DRV602PW | 14-Pin TSSOP |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

RECOMMENDED OPERATING CONDITIONS

| | MIN | TYP | MAX | UNIT |
|---|-----|-----|-----|----------|
| V _{DD} Supply voltage, DC Supply Voltage | 3 | 3.3 | 5.5 | V |
| V _{IH} High-level input voltage | | 60 | | % of VDD |
| V _{IL} Low-level input voltage | | 40 | | % of VDD |
| T _A Operating free-air temperature | –40 | | 85 | °C |

ELECTRICAL CHARACTERISTICS

 T_A = 25°C (unless otherwise noted)

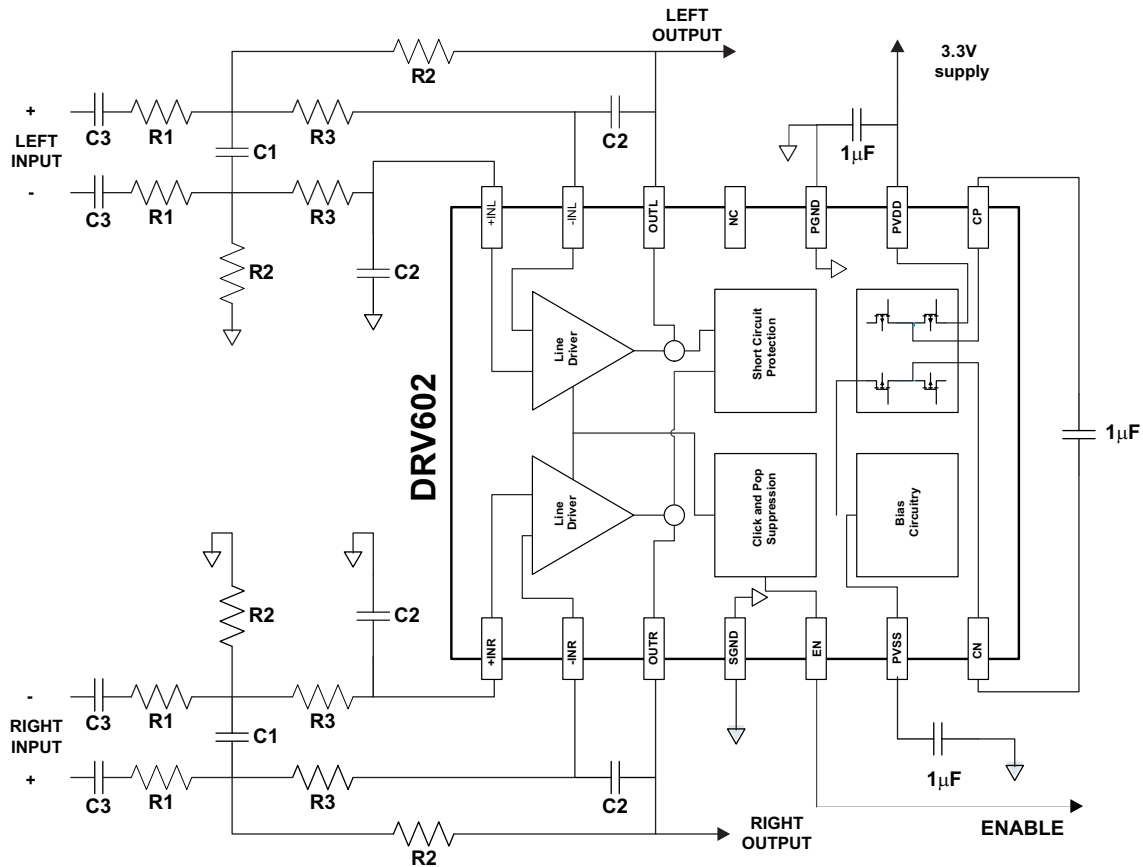
| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|---|------|------|-------|------|
| V _{OS} Output offset voltage | V _{DD} = 3 V to 5 V, Voltage follower - gain = 1 | | | 5 | mV |
| PSRR Supply Rejection Ratio | V _{DD} = 3.3 V to 5 V | | 88 | | dB |
| V _{OH} High-level output voltage | V _{DD} = 3.3 V, R _L = 2.5 kΩ | 3.10 | | | V |
| V _{OL} Low-level output voltage | V _{DD} = 3.3 V, R _L = 2.5 kΩ | | | –3.05 | V |
| I _{IH} High-level input current (EN) | V _{DD} = 5 V, V _I = V _{DD} | | | 1 | μA |
| I _{IL} Low-level input current (EN) | V _{DD} = 5 V, V _I = 0 V | | | 1 | μA |
| I _{DD} Supply Current | V _{DD} = 3.3 V, No load, EN = V _{DD} | 8 | 11 | | mA |
| | V _{DD} = 5 V, No load, EN = V _{DD} | | 12.5 | 20 | |
| | Shutdown mode, V _{DD} = 3 V to 5 V | | | 2 | mA |

OPERATING CHARACTERISTICS

$V_{DD} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$, $R_L = 2.5\text{ k}\Omega$, $C_{(PUMP)} = C_{(PVSS)} = 1\ \mu\text{F}$, $C_{IN} = 1\ \mu\text{F}$, $R_{IN} = 33\ \text{k}\Omega$, $R_{fb} = 68\text{ k}\Omega$ (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|-----|----------------|-----|---------------------|
| V _O Output Voltage (Outputs In Phase) | THD = 1%, V _{DD} = 3.3 V, f = 1 kHz | | 2.05 | | V _{rms} |
| | THD = 1%, V _{DD} = 5 V, f = 1 kHz | | 3.01 | | |
| THD+N Total harmonic distortion plus noise | V _O = 2 V _{rms} , f = 1 kHz V _O = 2 V _{rms} , f = 6.8 kHz | | 0.01% 0.05% | | |
| Crosstalk | V _O = 2 V _{rms} , f = 1 kHz | | -100 | | dB |
| I _O Output current limit | V _{DD} = 3.3 V | | 20 | | mA |
| R _{IN} Input resistor range | | 1 | 10 | 47 | k Ω |
| R _{fb} Feedback resistor range | | 4.7 | 20 | 100 | k Ω |
| Slew rate | | | 4.5 | | V/ μs |
| Maximum capacitive load | | | 220 | | pF |
| V _N Noise output voltage | A-weighted, BW 20Hz–22kHz | | 15 | | μV_{rms} |
| SNR Signal to noise ratio | V _O = 2 V _{rms} , THD+N = 0.1%, 22 kHz BW, A-weighted | | 102 | | dB |
| G _{BW} Unity Gain Bandwidth | | | 8 | | MHz |
| A _{VO} Open-loop voltage gain | | | 150 | | dB |
| F _{cp} Charge Pump frequency | | 225 | 450 | 675 | kHz |

APPLICATION CIRCUIT



R1 = 33k Ω , R2 = 68k Ω , R3 = 100k Ω , C1 = 150pF, C2 = 15pF, C3 = 1 μF

Differential input, single ended output, 2nd order filter. 40kHz –3dB frequency, Gain 2.06.

TYPICAL CHARACTERISTICS

$V_{DD} = 3.3V$, $T_A = 25^\circ C$, $C_{(PUMP)} = C_{(PVSS)} = 1 \mu F$, $C_{IN} = 1 \mu F$, $R_{IN} = 33 k\Omega$, $R_{fb} = 68 k\Omega$, $R_L = 2.5 k\Omega$ (unless otherwise noted)

TOTAL HARMONIC DISTORTION + NOISE
vs
OUTPUT VOLTAGE

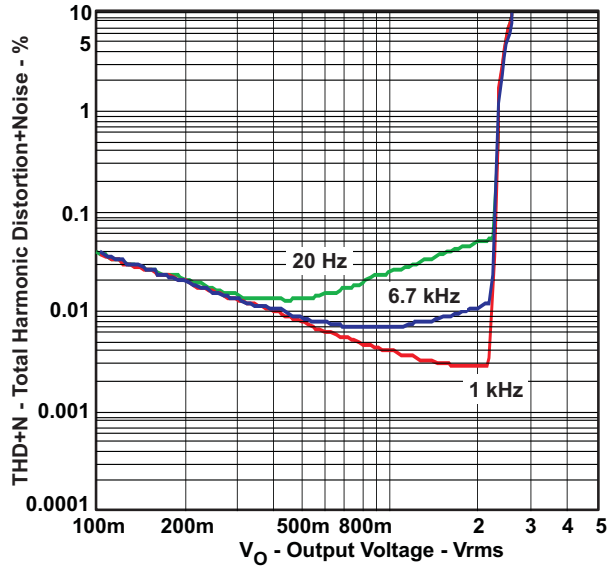


Figure 1.

TOTAL HARMONIC DISTORTION + NOISE
vs
FREQUENCY

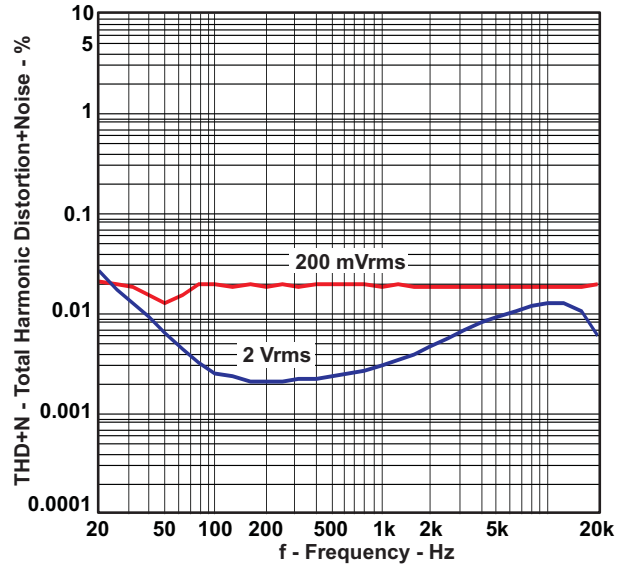


Figure 2.

FFT
vs
FREQUENCY

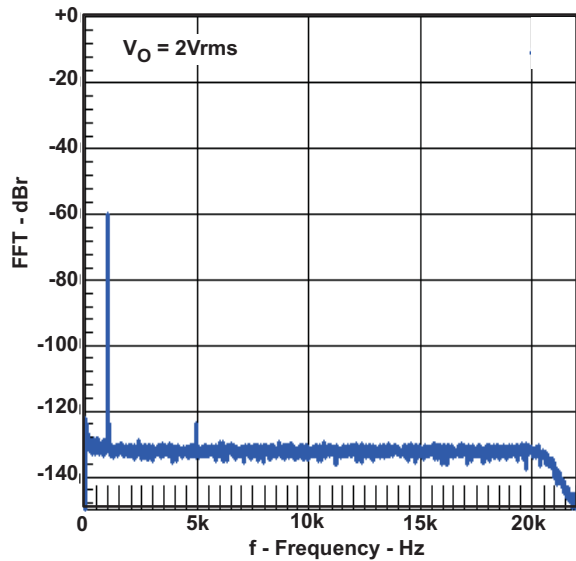


Figure 3.

QUIESCENT SUPPLY CURRENT
vs
SUPPLY VOLTAGE

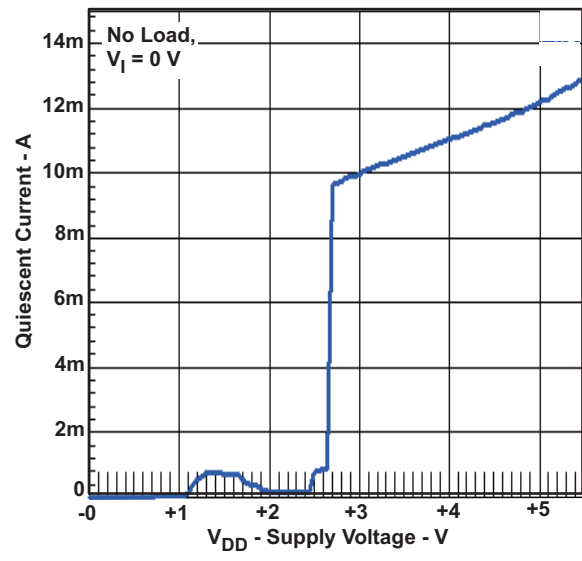


Figure 4.

APPLICATION INFORMATION

Line Driver Amplifiers

Single-supply line driver amplifiers typically require dc-blocking capacitors. The top drawing in [Figure 5](#) illustrates the conventional line driver amplifier connection to the load and output signal.

DC blocking capacitors are often large in value, and a mute circuit is needed during power up to minimize click & pop. The output capacitor and mute circuit consume PCB area and increase cost of assembly, and can reduce the fidelity of the audio output signal.

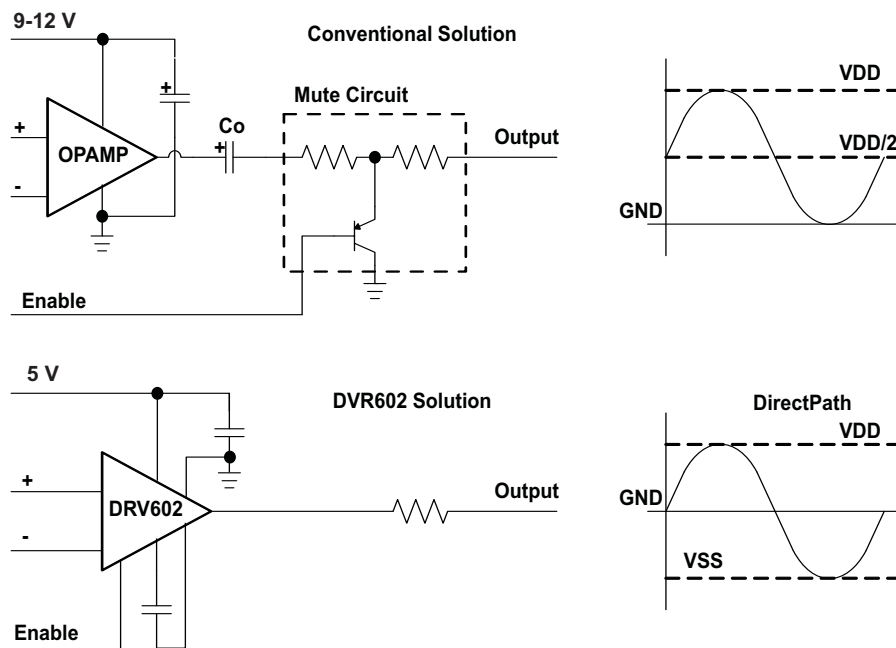


Figure 5. Conventional and DirectPath Line Driver

The DirectPath™ amplifier architecture operates from a single supply, but makes use of an internal charge pump to provide a negative voltage rail.

Combining the user provided positive rail and the negative rail generated by the IC, the device operates in what is effectively a split supply mode.

The output voltages are now centered at zero volts with the capability to swing to the positive rail or negative rail. The DirectPath amplifier requires no output dc blocking capacitors.

The bottom block diagram and waveform of [Figure 5](#) illustrate the ground-referenced Line Driver architecture. This is the architecture of the DRV602.

Charge Pump Flying Capacitor and PVSS Capacitor

The charge pump flying capacitor, C_{PUMP} , serves to transfer charge during the generation of the negative supply voltage. The PVSS capacitor must be at least equal to the charge pump capacitor in order to allow maximum charge transfer. Low ESR capacitors are an ideal selection, and a value of $1\mu\text{F}$ is typical. Capacitor values that are smaller than $1\mu\text{F}$ can be used, but the maximum output voltage may be reduced and the device may not operate to specifications.

Decoupling Capacitors

The DRV602 is a DirectPath Line Driver amplifier that require adequate power supply decoupling to ensure that the noise and total harmonic distortion (THD) are low. A good low equivalent-series-resistance (ESR) ceramic capacitor, typically $1\mu\text{F}$, placed as close as possible to the device PV_{DD} lead works best. Placing this decoupling capacitor close to the DRV602 is important for the performance of the amplifier. For filtering lower frequency noise signals, a $10\text{-}\mu\text{F}$ or greater capacitor placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device.

Gain setting resistors ranges

The gain setting resistors, R_{IN} and R_{fb} , must be chosen so that noise, stability and input capacitor size of the DRV602 is kept within acceptable limits. Voltage gain is defined as R_{fb} divided by R_{IN} .

Selecting values that are too low demands a large input ac-coupling capacitor, C_{IN} . Selecting values that are too high increases the noise of the amplifier. [Table 1](#) lists the recommended resistor values for different gain settings.

Table 1. Recommended Resistor Values

| INPUT RESISTOR VALUE, R_{IN} | FEEDBACK RESISTOR VALUE, R_{fb} | DIFFERENTIAL INPUT GAIN | INVERTING INPUT GAIN | NON INVERTING INPUT GAIN |
|--------------------------------|-----------------------------------|-------------------------|----------------------|--------------------------|
| 22 k Ω | 22 k Ω | 1.0 V/V | -1.0 V/V | 2.0 V/V |
| 15 k Ω | 30 k Ω | 1.5 V/V | -1.5 V/V | 2.5 V/V |
| 33 k Ω | 68 k Ω | 2.1 V/V | -2.1 V/V | 3.1 V/V |
| 10 k Ω | 100 k Ω | 10.0 V/V | -10.0 V/V | 11.0 V/V |

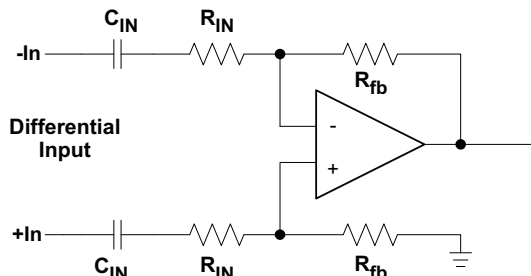


Figure 6. Differential Input

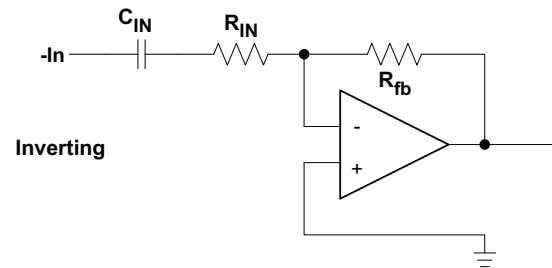


Figure 7. Inverting

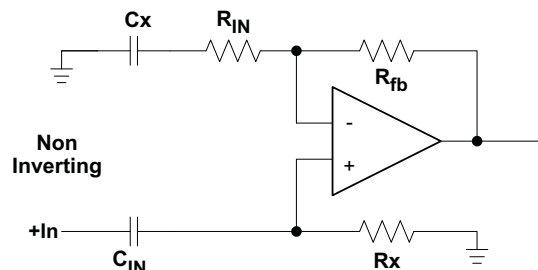


Figure 8. Non-Inverting

Input-Blocking Capacitors

DC input-blocking capacitors are required to be added in series with the audio signal into the input pins of the DRV602. These capacitors block the DC portion of the audio source and allow the DRV602 inputs to be properly biased to provide maximum performance. The input blocking capacitors also limit the DC gain to 1, limiting the DC-offset voltage at the output.

These capacitors form a high-pass filter with the input resistor, R_{IN} . The cutoff frequency is calculated using Equation 1. For this calculation, the capacitance used is the input-blocking capacitor and the resistance is the input resistor chosen from Table 1, then the frequency and/or capacitance can be determined when one of the two values are given.

$$f_{c_{IN}} = \frac{1}{2\pi R_{IN} C_{IN}} \quad \text{or} \quad C_{IN} = \frac{1}{2\pi f_{c_{IN}} R_{IN}} \quad (1)$$

Using the DRV602 as 2nd Order Filter

Several audio DACs used today require an external low-pass filter to remove out of band noise. This is possible with the DRV602 as it can be used like a standard OPAMP.

Several filter topologies can be implemented both single ended and differential. In Figure 9, a Multi FeedBack - MFB, with differential input and single ended input is shown.

An ac-coupling capacitor to remove dc-content from the source is shown, it serves to block any dc content from the source and lowers the dc-gain to 1 helping reducing the output dc-offset to minimum.

The component values can be calculated with the help of the TI FilterPro™ program available on the TI website at: <http://focus.ti.com/docs/toolsw/folders/print/filterpro.html>

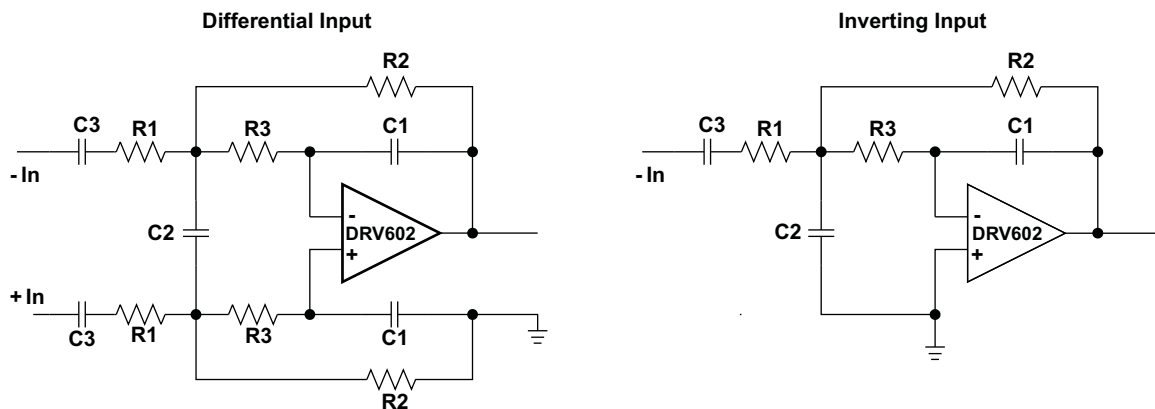


Figure 9. 2nd Order Active Low Pass Filter

The resistor values should have a low value for obtaining low noise, but should also have a high enough value to get a small size ac-coupling cap. With the proposed values, 33k, 68k, 100k, a DNR of 102dB can be achieved with a small 1 μ F input ac-coupling capacitor.

Pop-Free Power Up

Pop-free power up is ensured by keeping the EN (enable pin) low during power supply ramp up and down. The EN pin should be kept low until the input ac-coupling capacitors are fully charged before asserting the EN pin high; this way, proper precharge of the ac-coupling is performed, and pop-free power-up is achieved. [Figure 10](#) illustrates the preferred sequence.

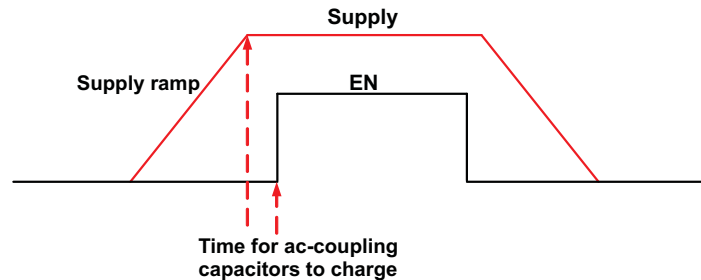


Figure 10. Power-Up Sequence

Capacitive Load

The DRV602 has the ability to drive a high capacitive load up to 220pF directly, higher capacitive loads can be accepted by adding a series resistor of 10Ω or larger.

Layout Recommendations

A proposed layout for the DRV602 can be seen in the DRV602EVM user's guide ([SLOU248](#)) and the Gerber files can be downloaded on www.ti.com, open the DRV602 product folder and look in the Tools and Software folder.

The gain setting resistors, R_{IN} and R_{fb} , must be placed close to the input pins to minimize the capacitive loading on these input pins and to ensure maximum stability of the DRV602. For the recommended PCB layout, see the DRV602EVM user's guide.

REVISION HISTORY

NOTE: Page numbers of current version may differ from previous versions.

| Changes from Revision A (December 2008) to Revision B | Page | | | | | | | | | | | | | | | | |
|--|-------------|---|-------------|---|---|--|---|---|---|--|---|--|---|--|---|--|---|
| • Changed crosstalk spec from -80dB to -100dB | 4 | | | | | | | | | | | | | | | | |
| <table style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="text-align: left;">Changes from Revision B (October 2009) to Revision C</th> <th style="text-align: right;">Page</th> </tr> </thead> <tbody> <tr> <td style="border-top: 1px solid black;">• Added "Pop-Free" to title and changed "pop-less" to "pop-free in description text strings.</td> <td style="text-align: right; vertical-align: bottom;">1</td> </tr> <tr> <td>• Added Output Voltage Feature bullet: "3Vrms With 5-V Supply Voltage"</td> <td style="text-align: right; vertical-align: bottom;">1</td> </tr> <tr> <td>• Changed "2Vrms" to "3Vrms" in Description Section</td> <td style="text-align: right; vertical-align: bottom;">1</td> </tr> <tr> <td>• Changed "5V_{PP}" to "8.5V_{PP}" in Description Section</td> <td style="text-align: right; vertical-align: bottom;">1</td> </tr> <tr> <td>• Changed Recommended Operating Conditions T_A range from "0 to 70 °C" to "-40 to 85°C"</td> <td style="text-align: right; vertical-align: bottom;">3</td> </tr> <tr> <td>• Changed Electrical Characteristics Test Conditions V_{DD} from "4.5 V" to "5 V"</td> <td style="text-align: right; vertical-align: bottom;">3</td> </tr> <tr> <td style="border-bottom: 1px solid black;">• Added "V_O" spec. for "V_{DD} = 5 V" to Operating Characteristics table</td> <td style="text-align: right; vertical-align: bottom; border-bottom: 1px solid black;">4</td> </tr> </tbody> </table> | | Changes from Revision B (October 2009) to Revision C | Page | • Added "Pop-Free" to title and changed "pop-less" to "pop-free in description text strings. | 1 | • Added Output Voltage Feature bullet: "3Vrms With 5-V Supply Voltage" | 1 | • Changed "2Vrms" to "3Vrms" in Description Section | 1 | • Changed "5V _{PP} " to "8.5V _{PP} " in Description Section | 1 | • Changed Recommended Operating Conditions T _A range from "0 to 70 °C" to "-40 to 85°C" | 3 | • Changed Electrical Characteristics Test Conditions V _{DD} from "4.5 V" to "5 V" | 3 | • Added "V _O " spec. for "V _{DD} = 5 V" to Operating Characteristics table | 4 |
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PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish | MSL Peak Temp (3) | Op Temp (°C) | Top-Side Markings (4) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-------------------------|------------------|----------------------|--------------|--------------------------|-------------------------|
| DRV602PW | ACTIVE | TSSOP | PW | 14 | 90 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | DRV602 | Samples |
| DRV602PWR | ACTIVE | TSSOP | PW | 14 | 2000 | Green (RoHS & no Sb/Br) | CU NIPDAU | Level-1-260C-UNLIM | -40 to 85 | DRV602 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| DRV602PWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| DRV602PWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.95 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |

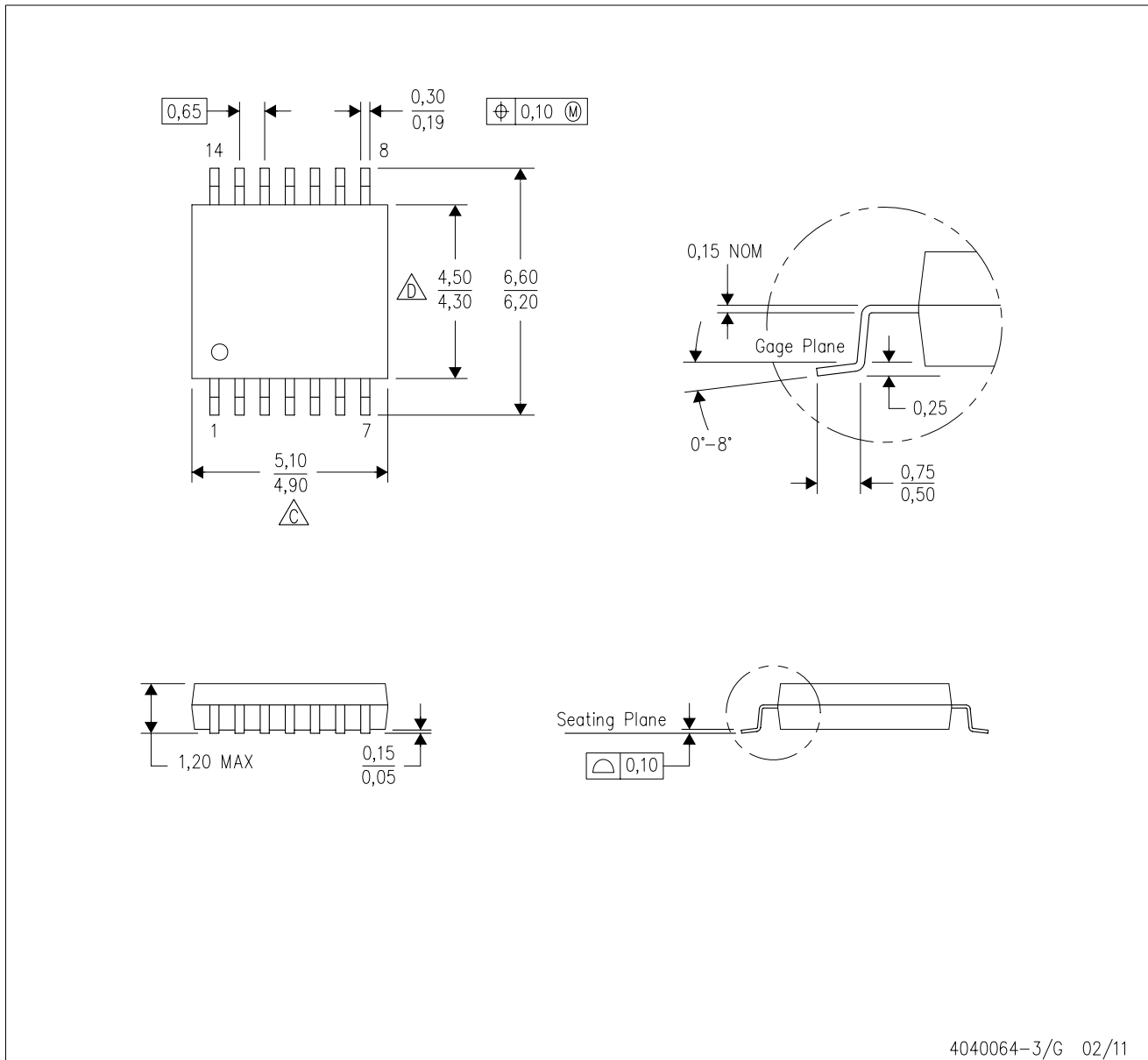
TAPE AND REEL BOX DIMENSIONS




*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------|--------------|-----------------|------|------|-------------|------------|-------------|
| DRV602PWR | TSSOP | PW | 14 | 2000 | 367.0 | 367.0 | 38.0 |
| DRV602PWR | TSSOP | PW | 14 | 2000 | 355.0 | 350.0 | 50.0 |

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 -  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 -  D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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